imall

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Gallium Arsenide CATV Amplifier Module

Features

- Specified for 79-, 112- and 132-Channel Loading
- Excellent Distortion Performance
- Higher Output Capability
- Built-in Input Diode Protection
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions
- Output Port Ring Wave Protection

Applications

- CATV Systems Operating in the 47 to 870 MHz Frequency Range
- Output Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications

Description

INFORMA'

CHIVE

- 24 Vdc Supply, 47 to 870 MHz, CATV GaAs Forward Power Doubler Amplifier Module
- Replaced MHW9227A. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

Table 1. Maximum Ratings

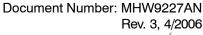
Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V _{in}	+70	dBmV
DC Supply Voltage	V _{CC}	+26	Vdc
Operating Case Temperature Range	T _C	-20 to +100	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

Table 2. ESD Maximum Ratings

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	200	200	V
Human Body Model per Mil. Std. 1686	2	2	kV

Table 3. Electrical Characteristics (V_{CC} = 24 Vdc, T_C = +45°C, 75 Ω system unless otherwise noted)

Charact	teristic	Symbol	Min	Тур	Max	Unit
Frequency Range		BW	47	—	870	MHz
Power Gain	870 MHz	G _p	21.5	22.1	22.7	dB
Slope	47-870 MHz	S	0	0.5	1.0	dB
Gain Flatness (40-870 MHz, Peak-to	—	_	—	0.7	dB	
Return Loss — Input/Output		IRL				dB
(Z _o = 75 Ohms)	47-500 MHz		20			
	501-750 MHz		18			
	751-870 MHz		16	_	—	



MHW9227AN

870 MHz

22.1 dB GAIN

132-CHANNEL

GaAs CATV AMPLIFIER MODULE

<u>√R</u>oHS

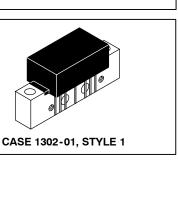




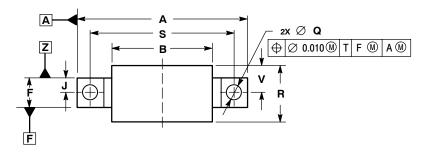


Table 3. Electrical Characteristics (V_{CC} = 24 Vdc, T_C = +45°C, 75 Ω system unless otherwise noted) (continued)

	Symbol	Min	Тур	Max	Unit	
Composite Second Order						dBc
(V _{out} = +48 dBmV/ch., Worst Case)	132-Channel FLAT	CSO ₁₃₂	_	-64	-62	
(V _{out} = +48 dBmV/ch., Worst Case)	112-Channel FLAT	CSO ₁₁₂		-66	-64	
$(V_{out} = +48 \text{ dBmV/ch., Worst Case})$	79-Channel FLAT	CSO ₇₉		-70	-68	
$(V_{out} = +56 \text{ dBmV} @ 870 \text{ MHz Equiv})$	112-Channel, 12 dB Tilt	CSO ₁₁₂		-65	-63	
$(V_{out} = +56 \text{ dBmV} @ 870 \text{ MHz Equiv})$	112-Channel, 13.5 dB Tilt	CSO ₁₁₂	_	-64	-62	
$(V_{out} = +56 \text{ dBmV} @ 870 \text{ MHz Equiv})$ $(V_{out} = +56 \text{ dBmV} @ 870 \text{ MHz Equiv})$	112-Channel, 17 dB Tilt	CSO ₁₁₂	_	-63	-61	
$(V_{out} = +58 \text{ dBmV} \oplus 870 \text{ MHz Equiv})$ $(V_{out} = +58 \text{ dBmV} \oplus 870 \text{ MHz Equiv})$	79-Channel, 12 dB Tilt	CSO ₇₉	_	-69	-67	
$(V_{out} = +58 \text{ dBmV} @ 870 \text{ MHz Equiv})$ $(V_{out} = +58 \text{ dBmV} @ 870 \text{ MHz Equiv})$	79-Channel, 13.5 dB Tilt	CSO ₇₉		-74	-72	
	79-Channel, 17 dB Tilt		_	-74	-72	
(V _{out} = +58 dBmV @ 870 MHz Equiv)	79-Charliner, 17 dB Thi	CSO ₇₉	_	-73	-71	
Cross Modulation Distortion @ Ch 2						dBc
(V _{out} = +48 dBmV/ch., FM = 55 MHz)	132-Channel FLAT	XMD ₁₃₂	_	-57	- 55	
(V _{out} = +48 dBmV/ch., FM = 55 MHz)	112-Channel FLAT	XMD ₁₁₂	_	-59	-57	
(V _{out} = +48 dBmV/ch., FM = 55 MHz)	79-Channel FLAT	XMD ₇₉		-62	-60	
(V _{out} = +56 dBmV @ 870 MHz Equiv)	112-Channel, 12 dB Tilt	XMD ₁₁₂	_	-53	-51	
(V _{out} = +56 dBmV @ 870 MHz Equiv)	112-Channel, 13.5 dB Tilt	XMD ₁₁₂		-55	-53	
$(V_{out} = +56 \text{ dBmV} @ 870 \text{ MHz Equiv})$	112-Channel, 17 dB Tilt	XMD ₁₁₂		-58	-56	
$(V_{out} = +58 \text{ dBmV} @ 870 \text{ MHz Equiv})$	79-Channel, 12 dB Tilt	XMD ₇₉	_	-60	-47	
$(V_{out} = +58 \text{ dBmV} @ 870 \text{ MHz Equiv})$	79-Channel, 13.5 dB Tilt	XMD ₇₉		-62	-60	
$(V_{out} = +58 \text{ dBmV} @ 870 \text{ MHz Equiv})$	79-Channel, 17 dB Tilt	XMD ₇₉	_	-67	-65	
		XWD /g		01	00	
Composite Triple Beat						dBc
(V _{out} = +48 dBmV/ch., Worst Case)	132-Channel FLAT	CTB ₁₃₂	—	-58	-56	
(V _{out} = +48 dBmV/ch., Worst Case)	112-Channel FLAT	CTB ₁₁₂	—	-62	-60	
(V _{out} = +48 dBmV/ch., Worst Case)	79-Channel FLAT	CTB ₇₉		-66	-64	
(V _{out} = +56 dBmV @ 870 MHz Equiv)	112-Channel, 12 dB Tilt	CTB ₁₁₂	—	-57	-55	
(V _{out} = +56 dBmV @ 870 MHz Equiv)	112-Channel, 13.5 dB Tilt	CTB ₁₁₂	—	-58	-56	
(V _{out} = +56 dBmV @ 870 MHz Equiv)	112-Channel, 17 dB Tilt	CTB ₁₁₂		-60	-58	
(V _{out} = +58 dBmV @ 870 MHz Equiv)	79-Channel, 12 dB Tilt	CTB ₇₉		-63	-61	
(V _{out} = +58 dBmV @ 870 MHz Equiv)	79-Channel, 13.5 dB Tilt	CTB ₇₉		-65	-63	
(V _{out} = +58 dBmV @ 870 MHz Equiv)	79-Channel, 17 dB Tilt	CTB ₇₉	—	-69	-67	
Noise Figure	50 MHz	NF	_	4.0	4.5	dB
	550 MHz		_	4.0	4.5	
	750 MHz			4.0	4.5	
	870 MHz			4.0	4.5	
	870 MHZ	-				
DC Current (V_{DC} = 24 V, T_{C} = 45°C)		IDC	410	425	440	mA



PACKAGE DIMENSIONS



2X U

->-

4X G

2X 6-32UNC-2B

E

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⊕ Ø 0.020 M T A M X

7X D

⊕ Ø 0.010 M Z T A M

С

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X

NOTES: 1. DIMENSIONS ARE IN INCHES. 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN MA		
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
Е	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100) BSC	2.540 BSC		
J	0.15	6 BSC	3.962 BSC		
Κ	0.315	0.355	8.001	9.017	
L	1.000) BSC	25.400 BSC		
Ν	0.165	5 BSC	4.191 BSC		
Ρ	0.100	BSC	2.540	BSC	
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500) BSC	38.100 BSC		
U	0.200	BSC	5.080 BSC		
V		0.250	6.3		
W	0.435		11.049		
X	0.400	BSC	10.16	0 BSC	
Y	0.152	0.163	3.861	4.140	
Ζ	0.009	0.011	0.229	0.279	

STYLE 1:
PIN 1. RF INPUT
2. GROUND
GROUND
DELETED
5. VDC
DELETED
7. GROUND
8. GROUND
9. RF OUTPUT

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Ρ

CASE 1302-01 **ISSUE E**

Ν

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RF Device Data

3

MHW9227AN



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